

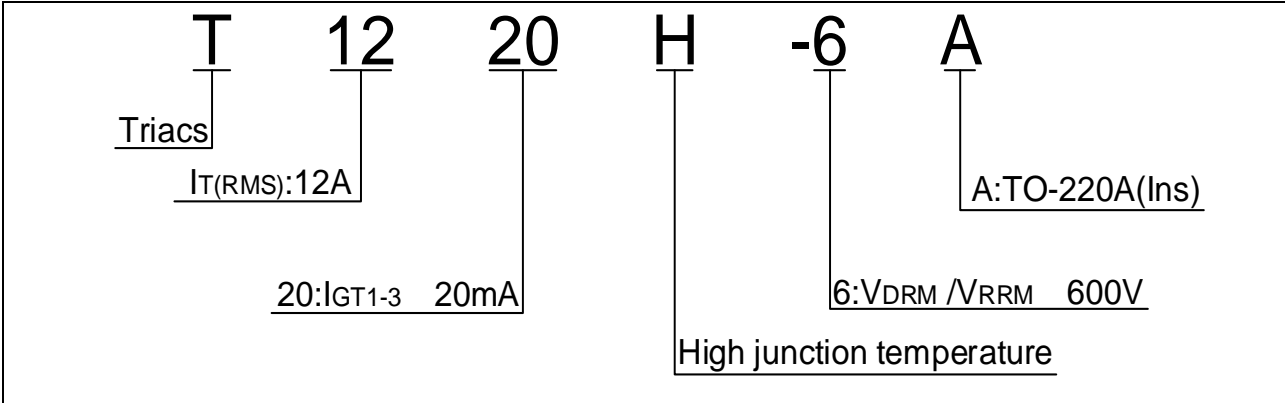
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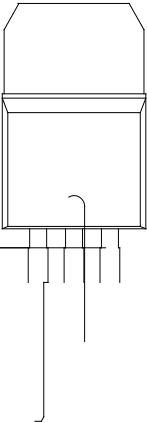


FIG.1: Maximum power dissipation versus RMS on-state current

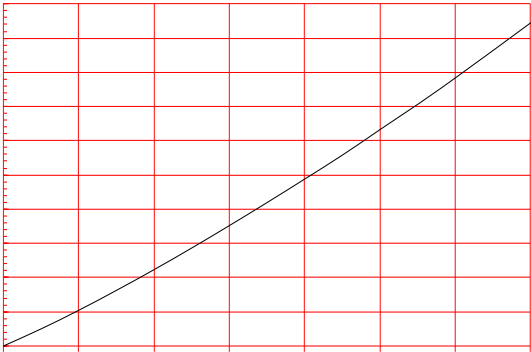


FIG.2: RMS on-state current versus case temperature

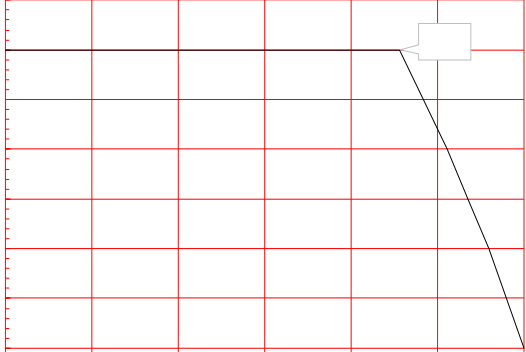
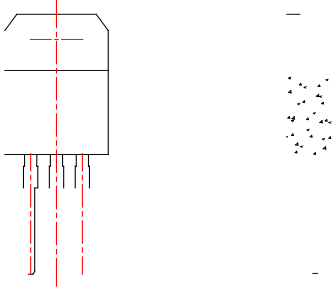


FIG.3: Surge peak on-state current versus number of cycles

FIG.4: On-state characteristic

PACKAGE MECHANICAL DATA 



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